

Electronic Acknowledgement Receipt

EFS ID:	5193367
Application Number:	10514429
International Application Number:	
Confirmation Number:	4375
Title of Invention:	PHOSPHOR SINGLE CRYSTAL SUBSTRATE AND METHOD FOR PREPARING THE SAME, AND NITRIDE SEMICONDUCTOR COMPONENT USING THE SAME
First Named Inventor/Applicant Name:	Robert Dwilinski
Customer Number:	25227
Filer:	Johnathan Bockman/Kathleen Libby
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File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		2045520338.pdf	382957 79f6c0b0b02b34577c56ab9e3e3f0f95432d51	yes	6
Multipart Description/PDF files in .zip description					
Document Description			Start	End	
Request for Continued Examination (RCE)			1	1	
Transmittal Letter			2	3	
Information Disclosure Statement (IDS) Filed (SB/08)			4	6	
Warnings:					
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2	Foreign Reference	JP05183189.pdf	384606 7d5d823e697c3a34c320373069f8eef30ef3d18a	no	7
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3	Foreign Reference	WO9428204A1.pdf	1324322 f80133e88e788704182330c7e7d12803c0c0504	no	33
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If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

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